,

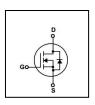
Features

- RDSON \leq 33m Ω @Vgs=10V, Id=10A
- · Advanced trench technology
- Excellent RDS(ON) and Low Gate Charge
- · Lead free product is acquired

Application

- Load Switch
- PWM Application
- Power management

SYMBOL





60V 20A N-Channel Enhancement Mode Power MOSFET

ASSEMBLY MESSAGE

Product Name	Package	Packaging
BXT330N06D	TO-252	Reel

ABSOLUTE MAXIMUM RATINGS (Tc=25°C unless otherwise noted)

Parameter		Symbol	Rating	Unit			
		- Cymbor -	TO-252				
Drain-Source Voltage		V _{DSS}	60	V			
D : 0 .		tinuous (T _C = 25°C)		20	А		
Drain Current	Con	tinuous (T _C = 100°C)	- I _D	14	А		
Drain Current	Pulsed (Note1)		Pulsed (Note1)		I _{DM}	80	А
Single Pulsed Avalanche Energy		alanche Energy		18	mJ		
Gate-Source Voltage		Source Voltage		±20	V		
Power Dissipation T _C =25°C		tion T _C =25°C		27.8	W		
Maximum Junction Temperature		um Junction Temperature		150	°C		
Storage Temperature Range		Temperature Range		-55 to 150	°C		

 $\begin{tabular}{ll} \textbf{Note:} & \textbf{1. Repetitive Rating: Pulse width limited by maximum junction temperature} \\ \end{tabular}$

THERMAL CHARACTERISTICS

Parameter	Symbol	Max.	linit
Faranietei		TO-252	Unit
Thermal Resistance, Junction to Case		5.4	°C / W



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ELECTRICAL CHARACTERISTICS (T_J=25°C,unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V, ID=250μA	60			V	
Zero Gate Voltage Drain Current	I _{DSS}	VDS=60V, VGS=0V			1	uA	
Gate-Body Leakage Current, Forward		VGS=20V			100	nA	
Gate-Body Leakage Current, Reverse	Igss	VGS=-20V			-100	nA	
ON CHARACTERISTICS			•				
Gate Threshold Voltage	V _{GS(TH)}	VDS=VGS, ID=250µA	1.0	1.6	2.5	V	
Drain-Source On-State Resistance	В	VGS=10V, ID=10A		26	33	mΩ	
Drain-Source On-State Resistance	$R_{DS(ON)}$	VGS=4.5V, ID=5A		33	45	mΩ	
DYNAMIC PARAMETERS	DYNAMIC PARAMETERS						
Input Capacitance	Ciss	VDC-25V VCC-0V		975		pF	
Output Capacitance	Coss	VDS=25V, VGS=0V,		61		pF	
Reverse Transfer Capacitance	C _{RSS} f=1.0MHz			56		pF	
SWITCHING PARAMETERS							
Turn-ON Delay Time	$t_{D(ON)}$			7.2		ns	
Turn-ON Rise Time	t _R	VDD=30V, ID=20A, VGS =		20		ns	
Turn-OFF Delay Time	t _{D(OFF)}	10V, RG=1.8Ω		15		ns	
Turn-OFF Fall-Time	t _F			24		ns	
Total Gate Charge(Note2)	Q_{G}	VDC -20V VCC -40V ID		24.5		nC	
Gate Source Charge	Q _{GS}	VDS =30V, VGS =10V, ID =10A		4.3		nC	
Gate Drain Charge	Q _{GD}	- TUA		6.4		nC	
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Drain-Source Diode Forward Voltage	V _{SD}	Is=20A, VGS=0V			1.2	V	
Diode Continuous Forward Current	ls				20	Α	
Maximum Pulsed Drain to Source Diode Forward Current	Іѕм				80	Α	
Body Diode Reverse Recovery Time	trr	. ,		29		ns	
Body Diode Reverse Recovery Charge	Qrr	IF=20A, dI/dt=100A/μs		50		nC	

Note: 2. Essentially independent of operating temperature



TYPICAL CHARACTERISTICS

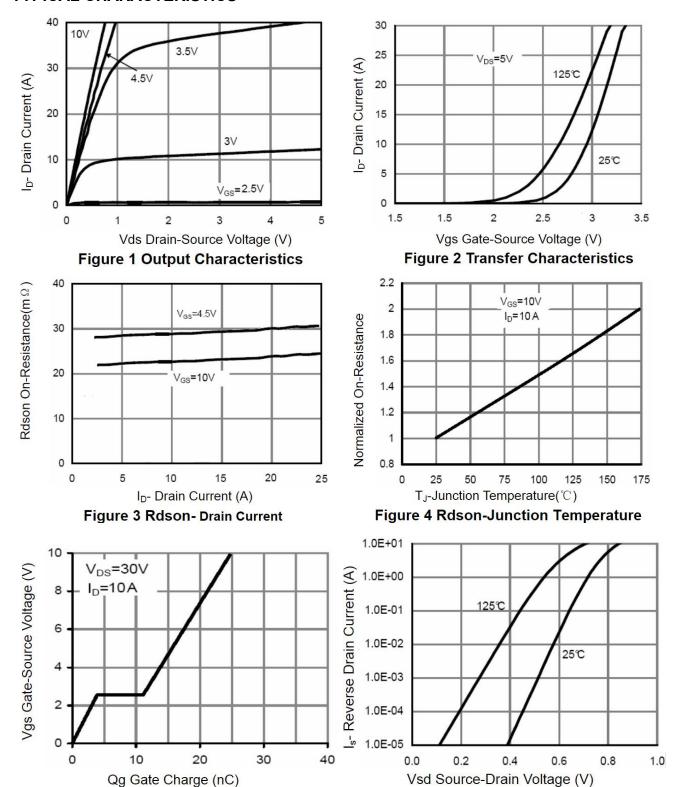


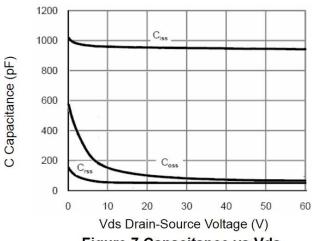
Figure 6 Source- Drain Diode Forward

Version: 1.0

Figure 5 Gate Charge



TYPICAL CHARACTERISTICS(Cont.)

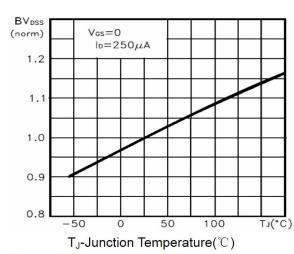


100.0

R_{DS(ON)}
Ilmited
100μs
100μ

Figure 7 Capacitance vs Vds

Figure 8 Safe Operation Area



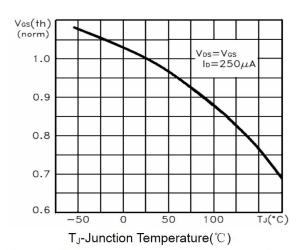
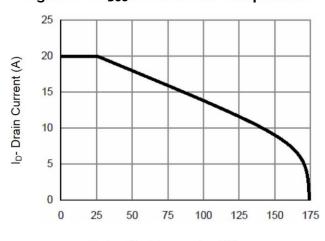


Figure 9 BV_{DSS} vs Junction Temperature

Figure 10 V_{GS(th)} vs Junction Temperature

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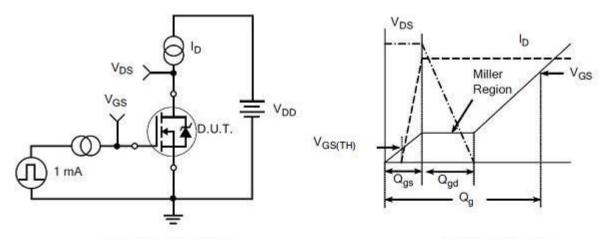


T_J-Junction Temperature(℃)

Figure 11 Current De-rating

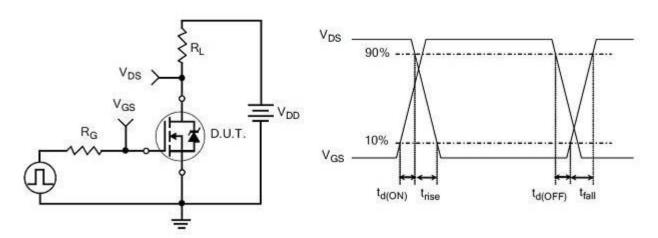


TEST CIRCUITS AND WAVEFORMS



Gate Charge Test Circuit

Gate Charge Waveform



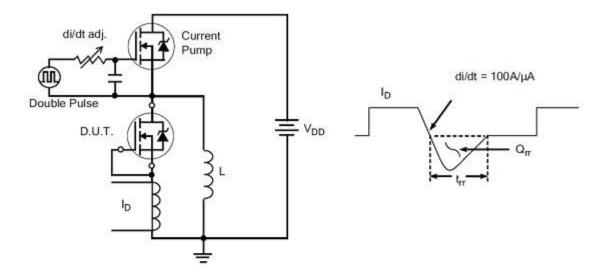
Resistive Switching Test Circuit

Resistive Switching Waveforms

Version: 1.0

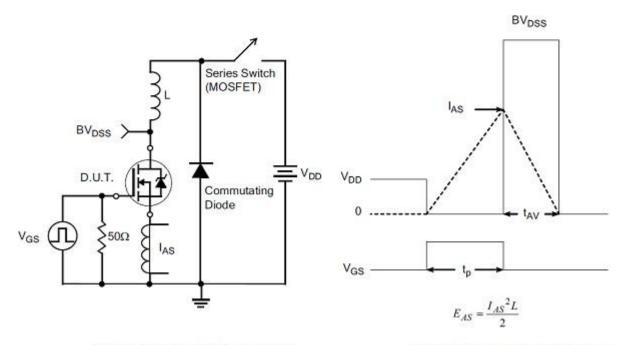


TEST CIRCUITS AND WAVEFORMS(Cont.)



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



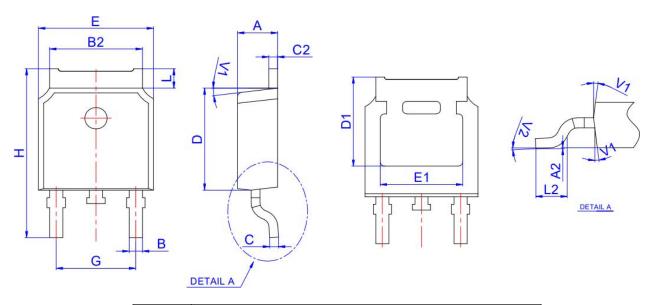
Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

Version: 1.0



TO-252 Package



			Dime	ensions		
Ref.		Millimete	ers	Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
В	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
С	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1		5.30REI	=	().209RE	F
Ε	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
Н	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°



Revision history

Document revision history

Date	Revision	Changes
25-Jan-2021	1.0	First release

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